

## Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
30V	33mΩ@10V	3.6A
	48mΩ@4.5V	

## Feature

- Trench power MV MOSFET technology
- High power and current handling capability
- Suffix "-Q1" for AEC-Q101

## Application

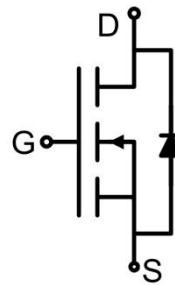
- PWM application
- Load switch

## Package

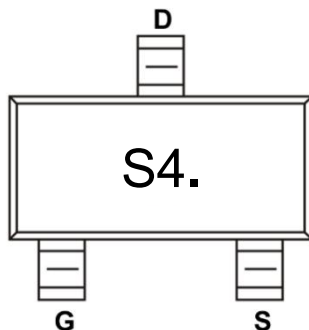


SOT-23

## Circuit diagram



## Marking



### Absolute maximum ratings (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	3.6	A
Continuous Drain Current (T <sub>A</sub> =70°C)	I <sub>D</sub> (70°C)	2.9	A
Pulsed Drain Current <sup>1)</sup>	I <sub>DM</sub>	15	A
Power Dissipation	P <sub>D</sub>	1	W
Thermal Resistance Junction to Ambient <sup>2)</sup>	R <sub>θJA</sub>	125	°C/W
Operating Junction Temperature	T <sub>J</sub>	-55 ~ +150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ +150	°C

### Electrical characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	30			V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V			1	μA
Gate-body leakage current	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±20V			±100	nA
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1	1.5	2.2	V
Drain-source on-resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.6A		26	33	mΩ
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 3A		39	48	
<b>Dynamic characteristics<sup>3)</sup></b>						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, f = 1MHz		314		pF
Output Capacitance	C <sub>oss</sub>			59		
Reverse Transfer Capacitance	C <sub>rss</sub>			48		
Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.6A		6.08		nC
Gate-Source Charge	Q <sub>gs</sub>			1.26		
Gate-Drain Charge	Q <sub>gd</sub>			1.32		
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 10V R <sub>L</sub> = 4.1A, R <sub>G</sub> = 3Ω		3.8		nS
Turn-on rise time	t <sub>r</sub>			23.2		
Turn-off delay time	t <sub>d(off)</sub>			7		
Turn-off fall time	t <sub>f</sub>			18.6		
<b>Source-Drain Diode characteristics</b>						
Diode Forward Current	I <sub>S</sub>				3.6	A
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 3.6A			1.2	V
Reverse Recovery Charge	T <sub>rr</sub>	I <sub>F</sub> = 3.6A, di/dt = -100A/μs		17.33		nS
Reverse Recovery Charge	Q <sub>rr</sub>			1.66		nC

Notes:

- 1) Pulse Test: Pulse Width ≤ 300μs, Duty cycle ≤ 2%.
- 2) R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.
- 3) Guaranteed by design, not subject to production testing.

## Typical Characteristics

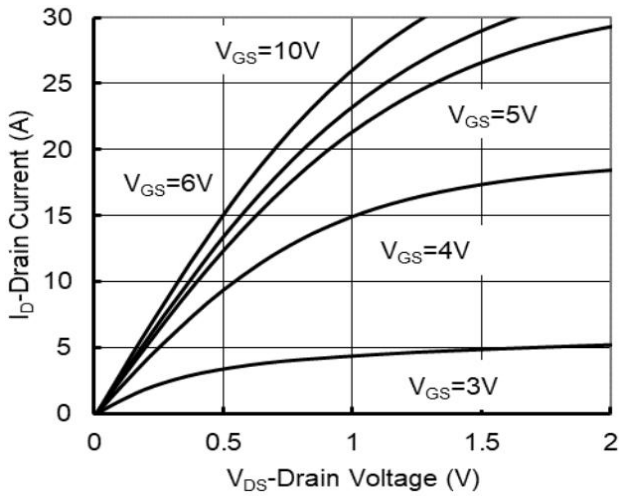


Figure1. Output Characteristics

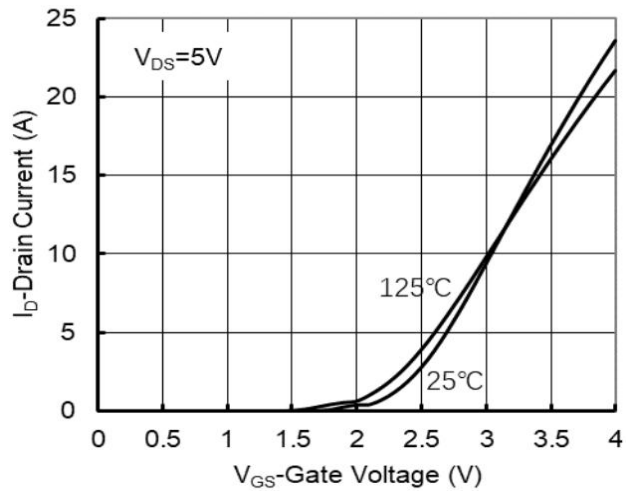


Figure2. Transfer Characteristics

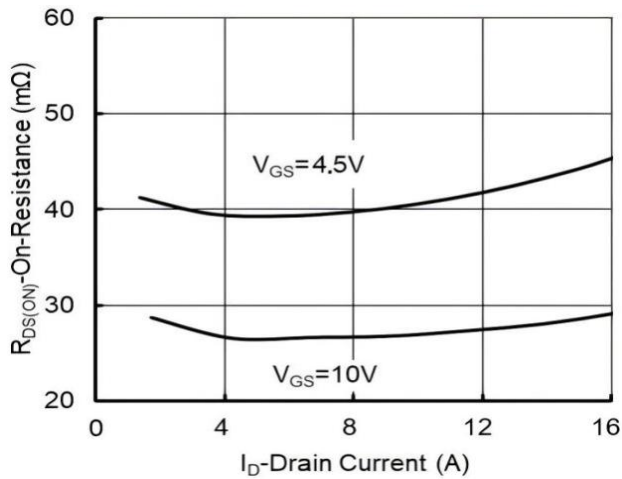


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

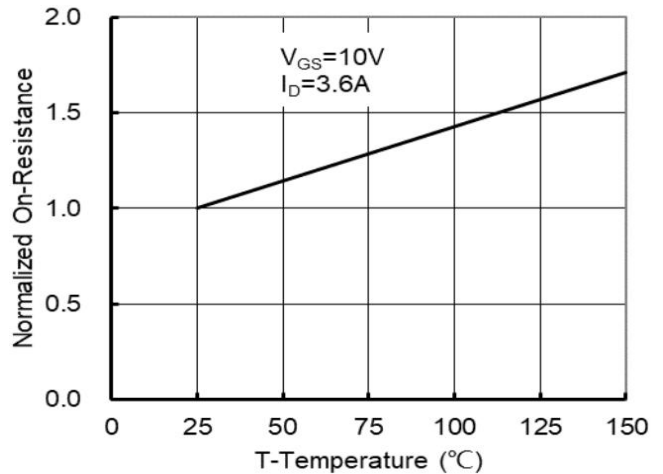


Figure 4: On-Resistance vs. Junction Temperature

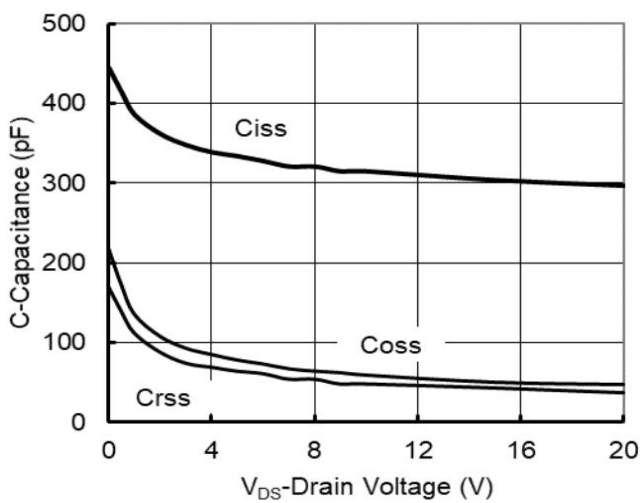


Figure5. Capacitance Characteristics

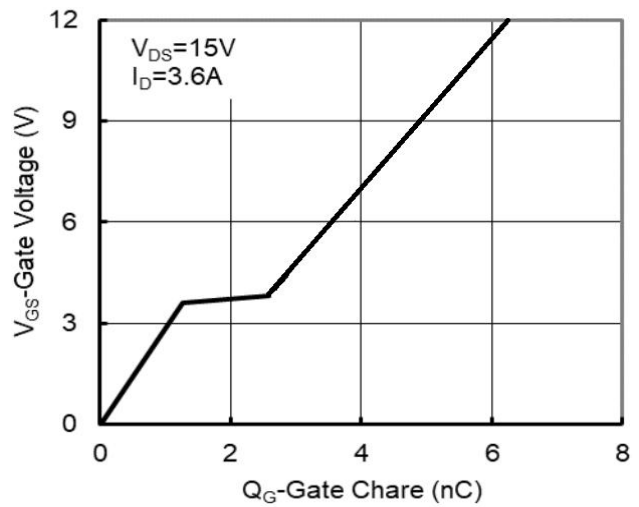


Figure6. Gate Charge

## Typical Characteristics

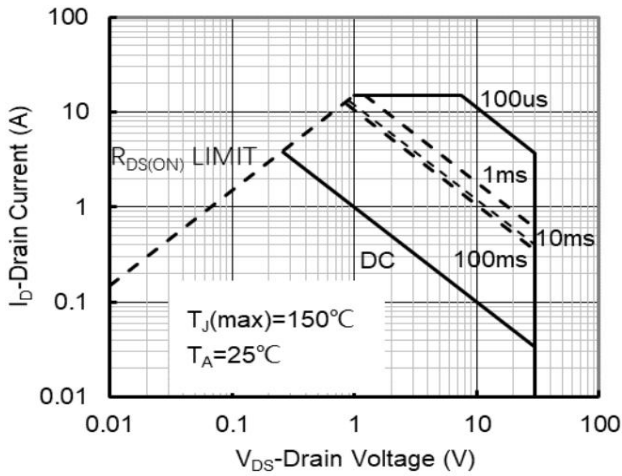


Figure 7. Safe Operation Area

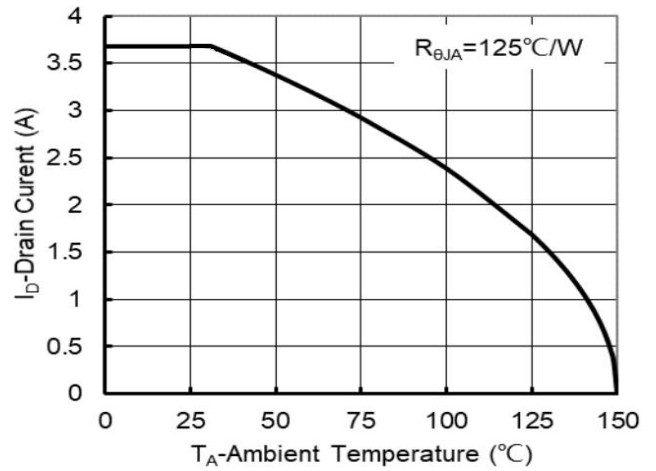


Figure 8. Maximum Continuous Drain Current vs Ambient Temperature

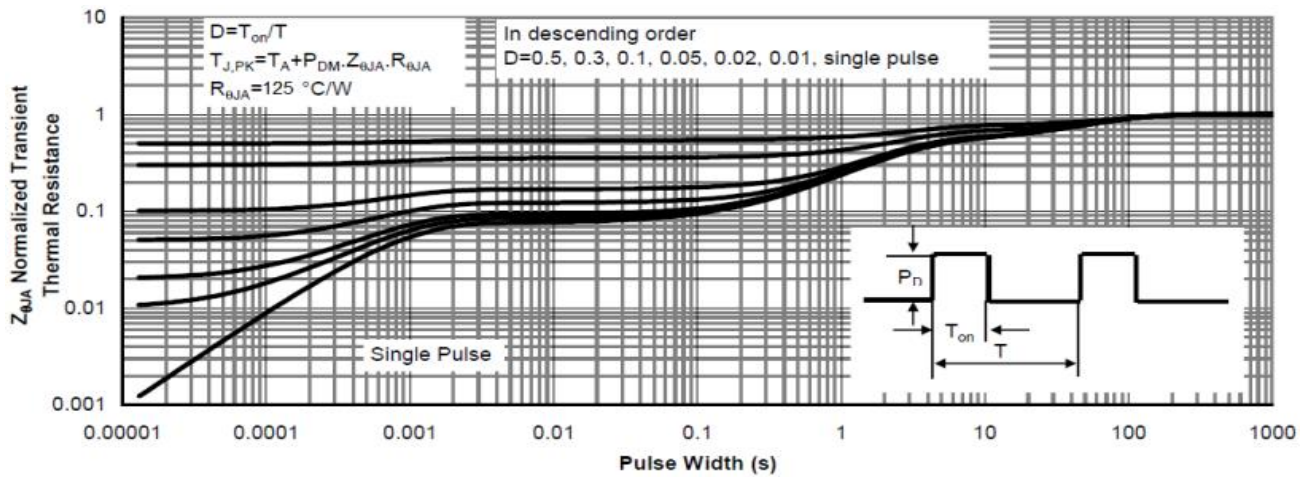
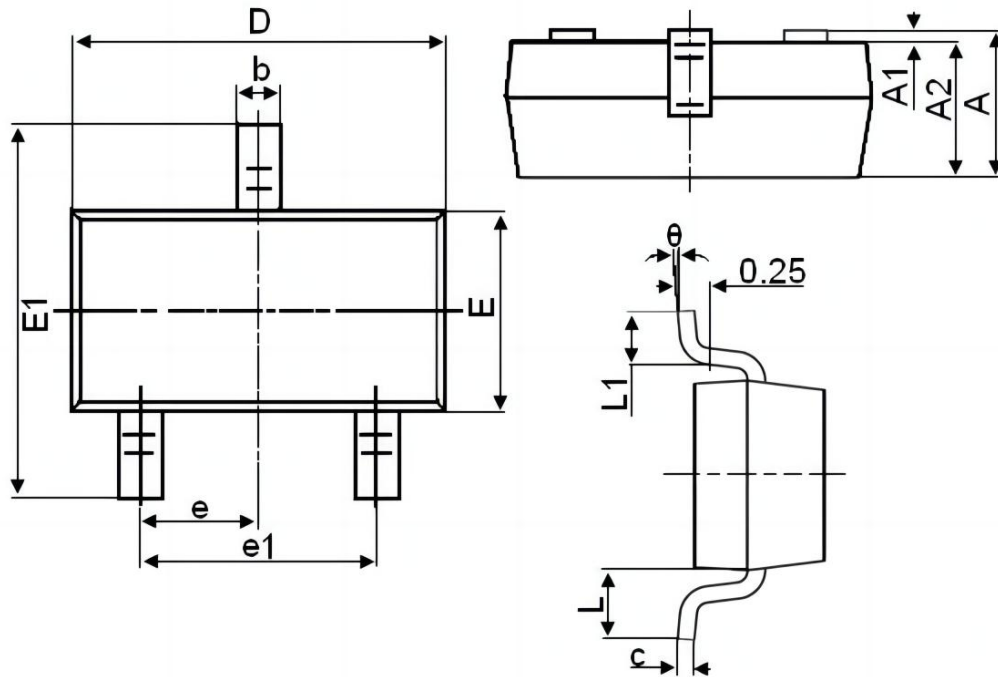


Figure 9. Normalized Maximum Transient Thermal Impedance

### SOT-23 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
C	0.100	0.200	0.004	0.008
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
$\theta$	0°	8°	0°	8°